CMOS Digital Integrated Circuits Silicon Monolithic

74VHCV374FT

1. Functional Description

- Octal Schmitt D-Type Flip-Flop with 3-State Outputs

2. General

The 74VHCV374FT is an advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input ($\overline{OE}$).

When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the 74VHCV374FT are capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity.

Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

3. Features

(1) AEC-Q100 (Rev. H) (Note 1)

(2) Wide operating temperature range: T_{opr} = -40 to 125 °C

(3) High speed: f_{MAX} = 185 MHz (typ.) at V_{CC} = 5.0 V

(4) Low power dissipation: I_{CC} = 2.0 μA (max) at T_a = 25 °C

(5) Wide operating voltage range: $V_{CC(opr)}$ = 1.8 V to 5.5 V

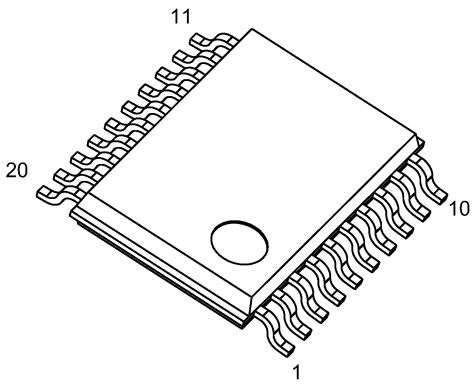
(6) Output current: $|I_{OH}|/I_{OL}$ = 16 mA (min)(V_{CC} = 4.5 V)

(7) Power-down protection is provided on all inputs and outputs.

(8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 374 type.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

4. Packaging



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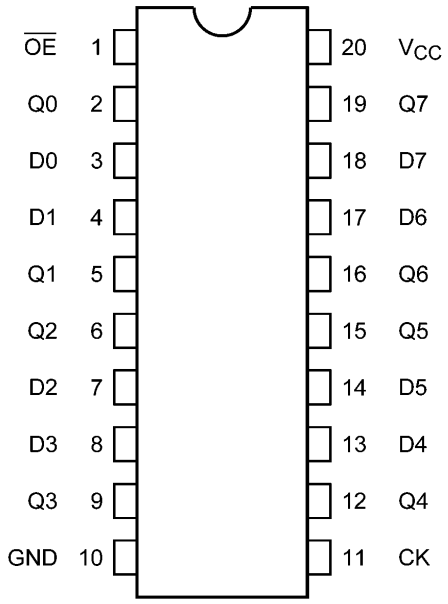
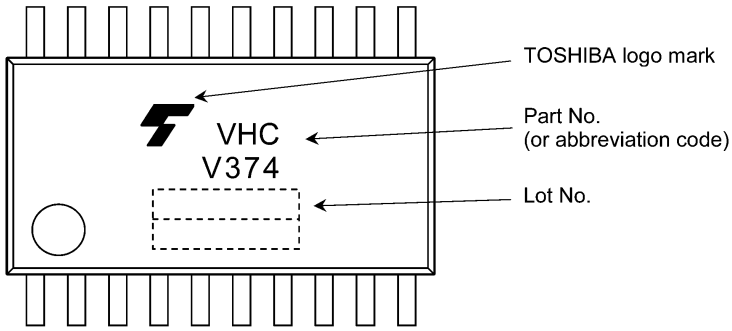
Start of commercial production
2015-02

5. Pin Assignment



6. Marking

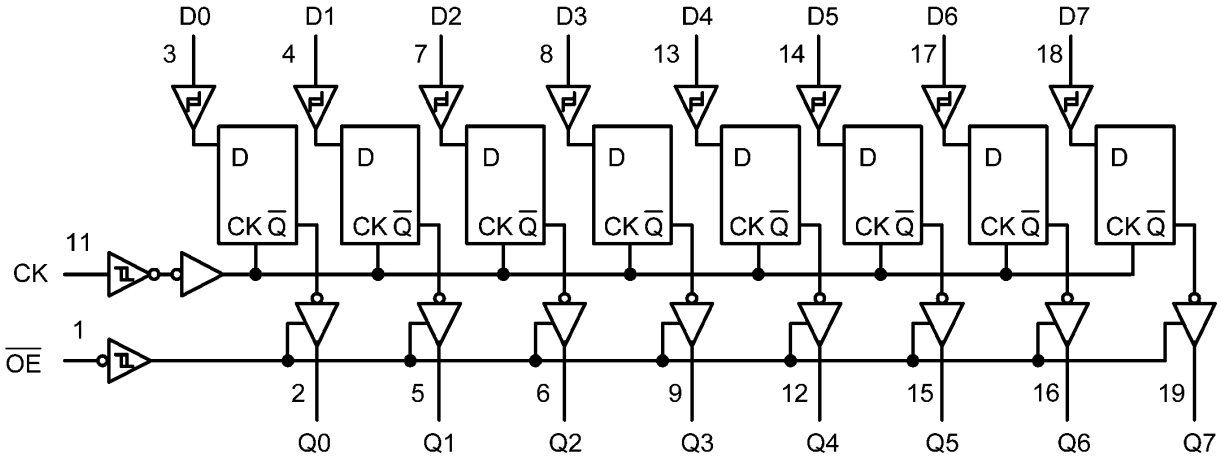


7. Truth Table

Inputs			Output
$\overline{OE}$	CK	D	
H	X	X	Z
L	↓	X	Qn
L	↑	L	L
L	↑	H	H

X: Don't care
Z: High impedance
Qn: No change

8. System Diagram



9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 7.0	V
Input voltage	V_{IN}		-0.5 to 7.0	V
Output voltage	V_{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V_{CC} + 0.5	
Input diode current	I_{IK}		-50	mA
Output diode current	I_{OK}	(Note 3)	±50	mA
Output current	I_{OUT}		±50	mA
Power dissipation	P_D	(Note 4)	180	mW
V_{CC}/ground current	I_{CC}/I_{GND}		±100	mA
Storage temperature	T_{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

Note 4: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Note	Rating	Unit
Supply voltage	V_{CC}	—		1.8 to 5.5	V
Input voltage	V_{IN}	—		0 to 5.5	V
Output voltage	V_{OUT}	—	(Note 1)	0 to 5.5	V
			(Note 2)	0 to V_{CC}	
Operating temperature	T_{opr}	—		-40 to 125	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 ± 0.3 V		0 to 20	ms/V
		V_{CC} = 5.0 ± 0.5 V		0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Typ.	Max	Unit
Positive threshold voltage	V_P	—		1.8	—	—	1.65	V
				2.3	—	—	1.85	
				3.0	—	—	2.20	
				4.5	—	—	3.15	
				5.5	—	—	3.85	
Negative threshold voltage	V_N	—		1.8	0.15	—	—	V
				2.3	0.45	—	—	
				3.0	0.90	—	—	
				4.5	1.35	—	—	
				5.5	1.65	—	—	
Hysteresis voltage	V_H	—		1.8	0.15	—	1.05	V
				2.3	0.20	—	1.10	
				3.0	0.30	—	1.20	
				4.5	0.40	—	1.40	
				5.5	0.50	—	1.60	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -50 μA	1.8	1.7	1.8	—	V
				3.0	2.9	3.0	—	
				4.5	4.4	4.5	—	
			I_{OH} = -8 mA	3.0	2.58	—	—	
			I_{OH} = -16 mA	4.5	3.94	—	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	1.8	—	0.0	0.1	V
				3.0	—	0.0	0.1	
				4.5	—	0.0	0.1	
			I_{OL} = 8 mA	3.0	—	—	0.36	
			I_{OL} = 16 mA	4.5	—	—	0.44	
3-state output OFF-state leakage current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = 0 to 5.5 V		1.8 to 5.5	—	—	±0.5	μA
Power-OFF leakage current	I_{OFF}	V_{IN}/V_{OUT} = 5.5 V		0	—	—	0.5	μA
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	2.0	μA

11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
Positive threshold voltage	V_P	—		1.8	—	1.65	V
				2.3	—	1.85	
				3.0	—	2.20	
				4.5	—	3.15	
				5.5	—	3.85	
Negative threshold voltage	V_N	—		1.8	0.15	—	V
				2.3	0.45	—	
				3.0	0.90	—	
				4.5	1.35	—	
				5.5	1.65	—	
Hysteresis voltage	V_H	—		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -50 μA	1.8	1.7	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I_{OH} = -8 mA	3.0	2.48	—	
			I_{OH} = -16 mA	4.5	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	1.8	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
			I_{OL} = 8 mA	3.0	—	0.44	
			I_{OL} = 16 mA	4.5	—	0.55	
3-state output OFF-state leakage current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = 0 to 5.5 V		1.8 to 5.5	—	±5.0	μA
Power-OFF leakage current	I_{OFF}	V_{IN}/V_{OUT} = 5.5 V		0	—	5.0	μA
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	20.0	μA

11.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
Positive threshold voltage	V_P	—		1.8	—	1.65	V
				2.3	—	1.85	
				3.0	—	2.20	
				4.5	—	3.15	
				5.5	—	3.85	
Negative threshold voltage	V_N	—		1.8	0.15	—	V
				2.3	0.45	—	
				3.0	0.90	—	
				4.5	1.35	—	
				5.5	1.65	—	
Hysteresis voltage	V_H	—		1.8	0.15	1.05	V
				2.3	0.20	1.10	
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -50 μA	1.8	1.7	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I_{OH} = -8 mA	3.0	2.40	—	
			I_{OH} = -16 mA	4.5	3.70	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	1.8	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
			I_{OL} = 8 mA	3.0	—	0.55	
			I_{OL} = 16 mA	4.5	—	0.65	
3-state output OFF-state leakage current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = 0 to 5.5 V		1.8 to 5.5	—	±20.0	μA
Power-OFF leakage current	I_{OFF}	V_{IN}/V_{OUT} = 5.5 V		0	—	20.0	μA
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	±2.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	40.0	μA

11.4. Timing Requirements (Unless otherwise specified, T_a = 25 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	V_{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}$,$t_{w(H)}$	2.5 ± 0.2	6.0	ns
		3.3 ± 0.3	5.0	
		5.0 ± 0.5	5.0	
Minimum setup time	t_S	2.5 ± 0.2	5.0	ns
		3.3 ± 0.3	4.5	
		5.0 ± 0.5	3.0	
Minimum hold time	t_h	2.5 ± 0.2	2.5	ns
		3.3 ± 0.3	2.0	
		5.0 ± 0.5	2.0	

11.5. Timing Requirements (Unless otherwise specified, T_a = -40 to 85 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	V_{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}$,$t_{w(H)}$	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	5.5	
		5.0 ± 0.5	5.0	
Minimum setup time	t_S	2.5 ± 0.2	5.5	ns
		3.3 ± 0.3	4.5	
		5.0 ± 0.5	3.0	
Minimum hold time	t_h	2.5 ± 0.2	2.5	ns
		3.3 ± 0.3	2.0	
		5.0 ± 0.5	2.0	

11.6. Timing Requirements (Unless otherwise specified, T_a = -40 to 125 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	V_{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}$,$t_{w(H)}$	2.5 ± 0.2	7.0	ns
		3.3 ± 0.3	5.5	
		5.0 ± 0.5	5.0	
Minimum setup time	t_S	2.5 ± 0.2	6.0	ns
		3.3 ± 0.3	4.5	
		5.0 ± 0.5	3.0	
Minimum hold time	t_h	2.5 ± 0.2	2.5	ns
		3.3 ± 0.3	2.0	
		5.0 ± 0.5	2.0	

11.7. AC Characteristics (Unless otherwise specified, T_a = 25 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Unit
Propagation delay time (CK-Q)	t_{PLH},t_{PHL}		—	2.5 ± 0.2	15	—	12.1	16.3	ns
					50	—	14.9	19.3	
				3.3 ± 0.3	15	—	7.1	12.7	
					50	—	9.2	16.2	
				5.0 ± 0.5	15	—	5.4	8.1	
					50	—	7.1	10.1	
3-state output enable time	t_{PZL},t_{PZH}		R_L = 1 kΩ	2.5 ± 0.2	15	—	9.4	15.9	ns
					50	—	12.3	18.8	
				3.3 ± 0.3	15	—	6.5	11.0	
					50	—	8.7	14.5	
				5.0 ± 0.5	15	—	4.5	7.6	
					50	—	6.2	9.6	
3-state output disable time	t_{PLZ},t_{PHZ}		R_L = 1 kΩ	2.5 ± 0.2	50	—	14.5	17.3	ns
				3.3 ± 0.3	50	—	10.9	14.0	
				5.0 ± 0.5	50	—	8.0	8.8	
Maximum clock frequency	f_{MAX}		—	2.5 ± 0.2	15	60	80	—	MHz
					50	50	65	—	
				3.3 ± 0.3	15	80	140	—	
					50	55	105	—	
				5.0 ± 0.5	15	130	185	—	
					50	85	140	—	
Output skew	t_{osLH},t_{osHL}	(Note 1)	—	2.5 ± 0.2	50	—	—	2.0	ns
				3.3 ± 0.3	50	—	—	1.5	
				5.0 ± 0.5	50	—	—	1.0	
Input capacitance	C_{IN}		—			—	4	10	pF
Output capacitance	C_{OUT}		—			—	6	—	pF
Power dissipation capacitance	C_{PD}	(Note 2)	—			—	21	—	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m - t_{PLH}n|$, $t_{osHL} = |t_{PHL}m - t_{PHL}n|$)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per latch)

And the total C_{PD} when n pcs. of latch operate can be gained by the following equation.

C_{PD} (total) = 11 + 10 × n

11.8. AC Characteristics
(Unless otherwise specified, T_a = -40 to 85 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	C_L (pF)	Min	Max	Unit
Propagation delay time (CK-Q)	t_{PLH},t_{PHL}		—	2.5 ± 0.2	15	1.0	19.0	ns
					50	1.0	23.0	
				3.3 ± 0.3	15	1.0	15.0	
					50	1.0	18.5	
				5.0 ± 0.5	15	1.0	9.5	
					50	1.0	11.5	
3-state output enable time	t_{PZL},t_{PZH}		R_L = 1 kΩ	2.5 ± 0.2	15	1.0	19.0	ns
					50	1.0	22.0	
				3.3 ± 0.3	15	1.0	13.0	
					50	1.0	16.5	
				5.0 ± 0.5	15	1.0	9.0	
					50	1.0	11.0	
3-state output disable time	t_{PLZ},t_{PHZ}		R_L = 1 kΩ	2.5 ± 0.2	50	1.0	19.0	ns
				3.3 ± 0.3	50	1.0	16.0	
				5.0 ± 0.5	50	1.0	10.0	
Maximum clock frequency	f_{MAX}		—	2.5 ± 0.2	15	50	—	MHz
					50	40	—	
				3.3 ± 0.3	15	70	—	
					50	50	—	
				5.0 ± 0.5	15	110	—	
					50	75	—	
Output skew	t_{osLH},t_{osHL}	(Note 1)	—	2.5 ± 0.2	50	—	2.0	ns
				3.3 ± 0.3	50	—	1.5	
				5.0 ± 0.5	50	—	1.0	
Input capacitance	C_{IN}		—			—	10	pF

Note 1: Parameter guaranteed by design. (t_{osLH} = $|t_{PLH}m-t_{PLH}n|$, t_{osHL} = $|t_{PHL}m-t_{PHL}n|$)

11.9. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	C_L (pF)	Min	Max	Unit
Propagation delay time (CK-Q)	t_{PLH},t_{PHL}		—	2.5 ± 0.2	15	1.0	21.0	ns
					50	1.0	25.5	
				3.3 ± 0.3	15	1.0	17.0	
					50	1.0	20.5	
				5.0 ± 0.5	15	1.0	11.0	
					50	1.0	13.0	
3-state output enable time	t_{PZL},t_{PZH}		R_L = 1 kΩ	2.5 ± 0.2	15	1.0	21.5	ns
					50	1.0	24.5	
				3.3 ± 0.3	15	1.0	15.0	
					50	1.0	18.5	
				5.0 ± 0.5	15	1.0	10.0	
					50	1.0	12.0	
3-state output disable time	t_{PLZ},t_{PHZ}		R_L = 1 kΩ	2.5 ± 0.2	50	1.0	20.5	ns
				3.3 ± 0.3	50	1.0	17.5	
				5.0 ± 0.5	50	1.0	11.0	
Maximum clock frequency	f_{MAX}		—	2.5 ± 0.2	15	40.0	—	MHz
					50	30.0	—	
				3.3 ± 0.3	15	60.0	—	
					50	40.0	—	
				5.0 ± 0.5	15	100.0	—	
					50	65.0	—	
Output skew	t_{osLH},t_{osHL}	(Note 1)	—	2.5 ± 0.2	50	—	2.0	ns
				3.3 ± 0.3	50	—	1.5	
				5.0 ± 0.5	50	—	1.0	
Input capacitance	C_{IN}		—			—	10	pF

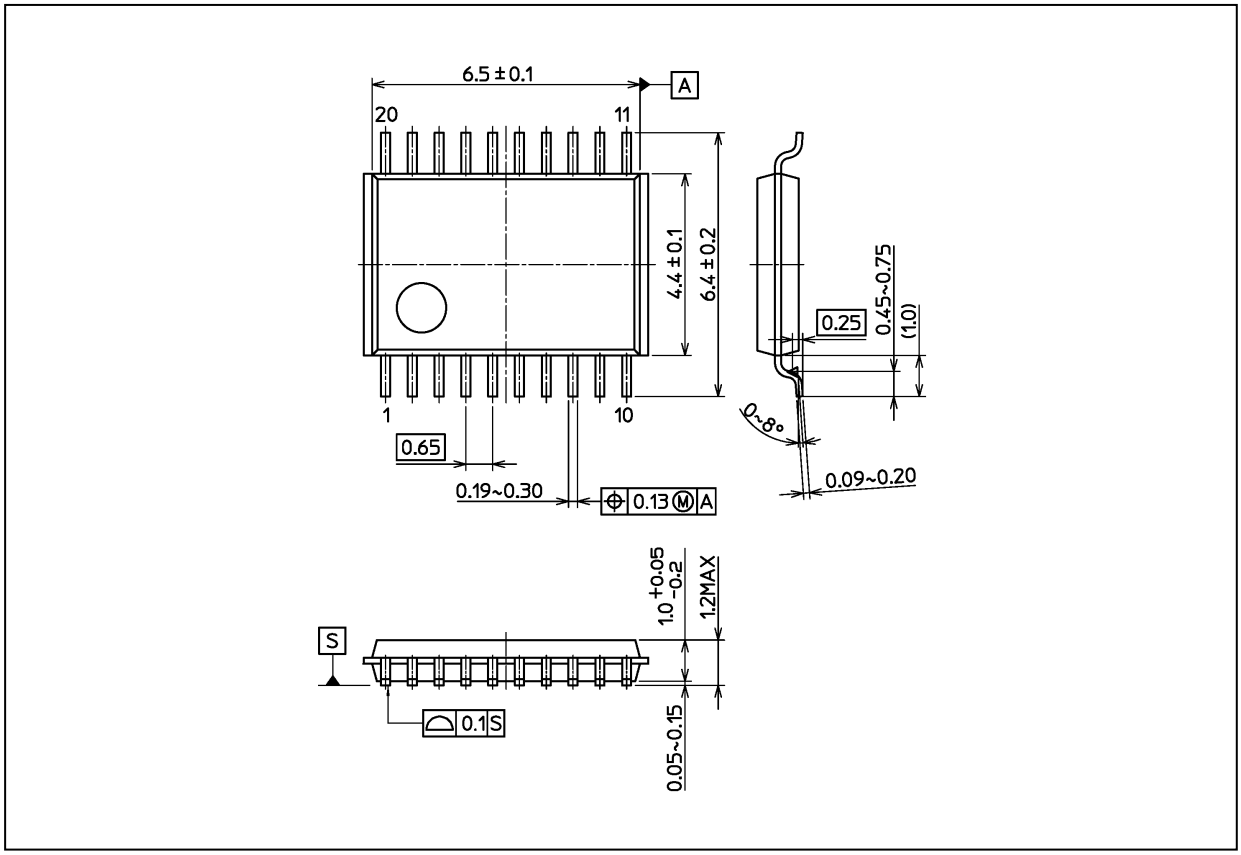
Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLHm} - t_{PLHn}|$, $t_{osHL} = |t_{PHLm} - t_{PHLn}|$)

11.10. Noise Characteristics (Unless otherwise specified, T_a = 25 °C, Input: $t_r = t_f$ = 3 ns)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Typ.	Max	Unit
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	3.3	0.3	—	V
			5.0	0.7	—	
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	3.3	-0.1	—	V
			5.0	-0.4	—	
Minimum high-level dynamic input voltage	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Maximum low-level dynamic input voltage	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

Package Name(s)
Nickname: TSSOP20B

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